

## **Features**

• Single-Supply Operation from +1.8V ~ +6V

• Rail-to-Rail Input / Output

Gain-Bandwidth Product: 1MHz (Typ)

Low Input Bias Current: 10pA (Typ)

Low Offset Voltage: 200µV (Max)

Quiescent Current: 44µA per Amplifier (Typ)

Embedded RF Anti-EMI Filter

• Operating Temperature: -40°C ~ +125°C

Small Package:

GS6011 Available in SOT23-5 and SC70-5 Packages GS6012 Available in SOP-8 and MSOP-8 Packages GS6014 Available in SOP-14 and TSSOP-14 Packages

## **General Description**

The GS601X family have a high gain-bandwidth product of 1MHz, a slew rate of  $0.6V/\mu s$ , and a quiescent current of 44 $\mu$ A/amplifier at 5V. The GS601X family is designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 200 $\mu$ V for GS601X family. They are specified over the extended industrial temperature range (-40 $^{\circ}$ C to +125 $^{\circ}$ C). The operating range is from 1.8V to 6V. The GS6011 single is available in Green SC70-5 and SOT23-5 packages. The GS6012 dual is available in Green SOP-8 and MSOP-8 packages. The GS6014 Quad is available in Green SOP-14 and TSSOP-14 packages.

# **Applications**

- ASIC Input or Output Amplifier
- Sensor Interface
- Medical Communication
- Smoke Detectors

- Audio Output
- Piezoelectric Transducer Amplifier
- Medical Instrumentation
- Portable Systems

## **Pin Configuration**

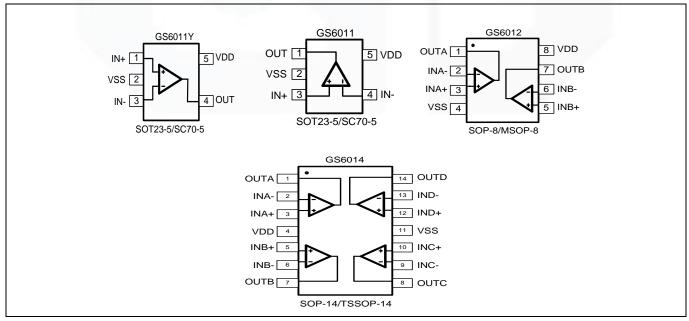


Figure 1. Pin Assignment Diagram





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## **Absolute Maximum Ratings**

Condition	Min	Max		
Power Supply Voltage (V <sub>DD</sub> to Vss)	-0.5V	+7.5V		
Analog Input Voltage (IN+ or IN-)	Vss-0.5V	V <sub>DD</sub> +0.5V		
PDB Input Voltage	Vss-0.5V	+7V		
Operating Temperature Range	-40°C	+125°C		
Junction Temperature	+160	)°C		
Storage Temperature Range	-55°C	+150°C		
Lead Temperature (soldering, 10sec)	+260	+260°C		
Package Thermal Resistance (T <sub>A</sub> =+25℃)				
SOP-8, θ <sub>JA</sub>	125°C	C/W		
MSOP-8, θ <sub>JA</sub>	216°0	C/W		
SOT23-5, θ <sub>JA</sub>	190°C	C/W		
SC70-5, θ <sub>JA</sub>	333°0	333°C/W		
ESD Susceptibility				
НВМ	±2H	<b>〈</b> V		
CDM $\pm 2$ KV		<v< td=""></v<>		
Latch up	±350	)mA		

**Note:** Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# **Package/Ordering Information**

MODEL	CHANNEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
		GS6011-CR	SC70-5	Tape and Reel,3000	6011
		GS6011-TR	SOT23-5	Tape and Reel,3000	6011
GS6011	Single	GS6011Y-CR	SC70-5	Tape and Reel,3000	6011Y
		GS6011Y-TR	SOT23-5	Tape and Reel,3000	6011Y
000040		GS6012-SR	SOP-8	Tape and Reel,4000	GS6012
GS6012	GS6012 Dual	GS6012-MR	MSOP-8	Tape and Reel,3000	GS6012
000044	O. a. d.	GS6014-TR	TSSOP-14	Tape and Reel,3000	GS6014
GS6014	Quad	GS6014-SR	SOP-14	Tape and Reel,2500	GS6014







## **Electrical Characteristics**

(At VS = +5V, RL = 100k $\Omega$  connected to VS/2, and VOUT = VS/2,  $T_A$  = 25  $^{\circ}$ C, unless otherwise noted.)

PARAMETER	SYMBOL CONDITIONS		GS6011/2/4				
			TYP	MAX	MIN	UNITS	
INPUT CHARACTERISTICS					•		
Input Offset Voltage	Vos	V <sub>CM</sub> = V <sub>S</sub> /2	50	200	-200	μV	
Input Bias Current	I <sub>B</sub>		10	100	-100	pA	
Input Offset Current	los		1			pA	
Common-Mode Voltage Range	V <sub>CM</sub>	Vs = 5.5V	-0.1 to +5.6			V	
Common Mode Dejection Datio	CMDD	$V_S = 5.5V$ , $V_{CM} = -0.1V$ to 4V	70		62	dB	
Common-Mode Rejection Ratio	CMRR	V <sub>S</sub> = 5.5V, V <sub>CM</sub> = -0.1V to 5.6V	68		56		
On an Lagar Vallaga Onia	Δ.	$R_L = 5k\Omega$ , $V_O = +0.1V$ to +4.9V	80		70	dB	
Open-Loop Voltage Gain	A <sub>OL</sub>	$R_L = 10k\Omega$ , $V_O = +0.1V$ to +4.9V	100		94		
Input Offset Voltage Drift	$\Delta V_{OS}/\Delta_T$		2.7			μV/°C	
OUTPUT CHARACTERISTICS							
	V <sub>OH</sub>	R <sub>L</sub> = 100kΩ	4.997	1		mV	
Output Voltage Swing from Rail	VoL	R <sub>L</sub> = 100kΩ	5	30		mV	
	V <sub>OH</sub>	R <sub>L</sub> = 10kΩ	4.992			mV	
	VoL	R <sub>L</sub> = 10kΩ	8	30		mV	
	Isink		59		40		
Output Current	I <sub>SINK</sub>	$R_L = 10\Omega$ to $V_S/2$	70		40	- mA	
POWER SUPPLY					I		
O					1.8	V	
Operating Voltage Range				6		V	
Power Supply Rejection Ratio	PSRR	$V_S = +2.5V \text{ to } +6V, V_{CM} = +0.5V$	82		60	dB	
Quiescent Current / Amplifier	ΙQ		44	75	30	μΑ	
DYNAMIC PERFORMANCE (CL	= 100pF)						
Gain-Bandwidth Product	GBP		1			MHz	
Slew Rate	SR	G = +1, 2V Output Step	0.6			V/µs	
Settling Time to 0.1%	ts	G = +1, 2V Output Step	5.3			μs	
Overload Recovery Time		V <sub>IN</sub> ·Gain = V <sub>S</sub>	2.6			μs	
NOISE PERFORMANCE					ı	1	
		f = 1kHz	27			$nV/\sqrt{Hz}$	
Voltage Noise Density	e <sub>n</sub> f = 10kHz		20			$nV/\sqrt{Hz}$	







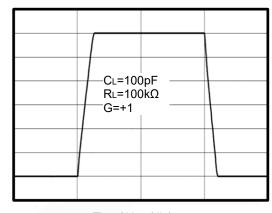
Output Voltage (250mV/div)

# **Typical Performance characteristics**

At  $T_A$ =+25°C,  $V_S$ =5V,  $R_L$ =100K $\Omega$  connected to  $V_S$ /2 and  $V_{OUT}$ =  $V_S$ /2, unless otherwise noted.

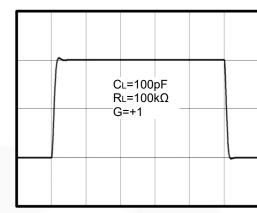
Output Voltage (50mV/div)





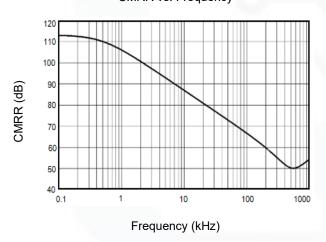
Time(10µs/div)

Small Signal Transient Response

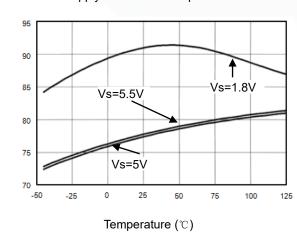


Time(2µs/div)

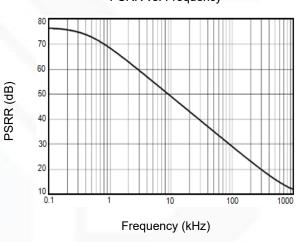
CMRR vs. Frequency



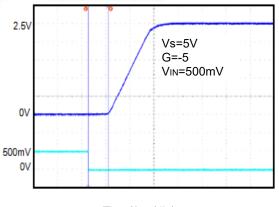
Supply Current vs. Temperature



PSRR vs. Frequency



Overload Recovery Time



Time(2µs/div)

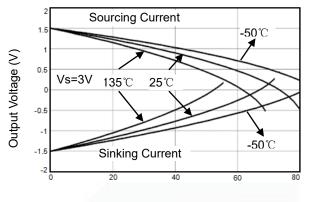


Supply Current (µA)

# **Typical Performance characteristics**

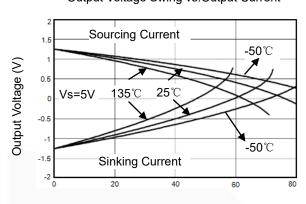
At  $T_A$ =+25°C,  $R_L$ =100K $\Omega$  connected to  $V_S$ /2 and  $V_{OUT}$ =  $V_S$ /2, unless otherwise noted.





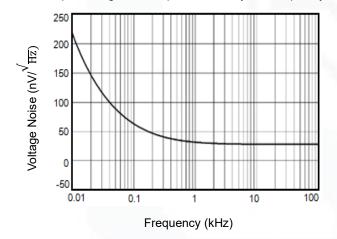
Output Current(mA)

Output Voltage Swing vs.Output Current

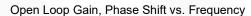


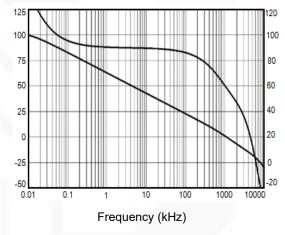
Output Current(mA)

Input Voltage Noise Spectral Density vs. Frequency



Open Loop Gain (dB)





Dhaca Shift (Dadrage)



## **Application Note**

#### Size

GS601X family series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the GS601X family packages save space on printed circuit boards and enable the design of smaller electronic products.

### **Power Supply Bypassing and Board Layout**

GS601X family series operates from a single 1.8V to 6V supply or dual  $\pm 0.9V$  to  $\pm 3V$  supplies. For best performance, a  $0.1\mu F$  ceramic capacitor should be placed close to the  $V_{DD}$  pin in single supply operation. For dual supply operation, both  $V_{DD}$  and  $V_{SS}$  supplies should be bypassed to ground with separate  $0.1\mu F$  ceramic capacitors.

### **Low Supply Current**

The low supply current (typical 44µA per channel) of GS601X family will help to maximize battery life. They are ideal for battery powered systems.

### **Operating Voltage**

GS601X family operates under wide input supply voltage (1.8V to 6V). In addition, all temperature specifications apply from - 40 °C to +125 °C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-lon battery lifetime.

### Rail-to-Rail Input

The input common-mode range of GS601X family extends 100mV beyond the supply rails ( $V_{SS}$ -0.1V to  $V_{DD}$ +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

#### **Rail-to-Rail Output**

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of GS601X family can typically swing to less than 10mV from supply rail in light resistive loads (>100k $\Omega$ ), and 60mV of supply rail in moderate resistive loads (10k $\Omega$ ).

### **Capacitive Load Tolerance**

The GS601X family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2 shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

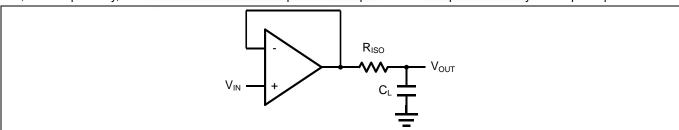


Figure 2 Indirectly Driving a Capacitive Load Using Isolation Resistor









The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. However, if there is a resistive load  $R_L$  in parallel with the capacitive load, a voltage divider (proportional to  $R_{ISO}/R_L$ ) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2.  $R_F$  provides the DC accuracy by feed-forward the  $V_{IN}$  to  $R_L$ .  $C_F$  and  $R_{ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of  $C_F$ . This in turn will slow down the pulse response.

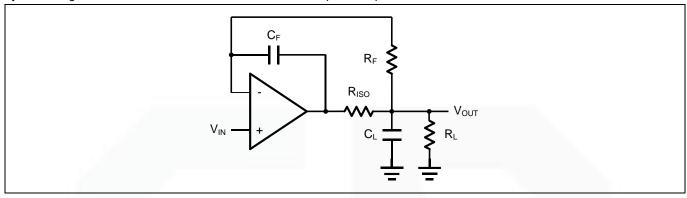


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy







# **Typical Application Circuits**

## **Differential amplifier**

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using GS601X family.

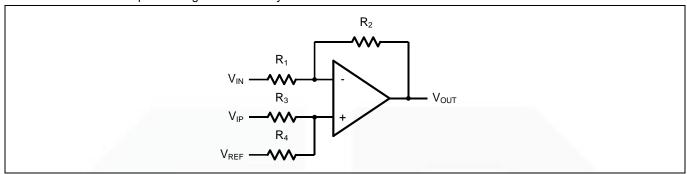


Figure 4. Differential Amplifier

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{\mathbb{N}} - \frac{R_2}{R_1} V_{\mathbb{P}} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e. R<sub>1</sub>=R<sub>3</sub> and R<sub>2</sub>=R<sub>4</sub>), then

$$V_{\text{OUT}} = \frac{R_2}{R_1} (V_{\text{IP}} - V_{\text{IN}}) + V_{\text{REF}}$$

## **Low Pass Active Filter**

The low pass active filter is shown in Figure 5. The DC gain is defined by  $-R_2/R_1$ . The filter has a -20dB/decade roll-off after its corner frequency  $f_C=1/(2\pi R_3C_1)$ .

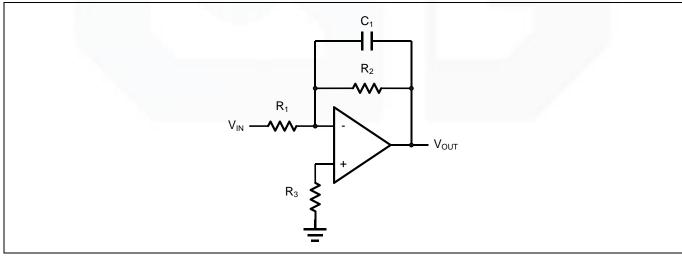


Figure 5. Low Pass Active Filter





## **Instrumentation Amplifier**

The triple GS601X family can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of  $R_2/R_1$ . The two differential voltage followers assure the high input impedance of the amplifier.

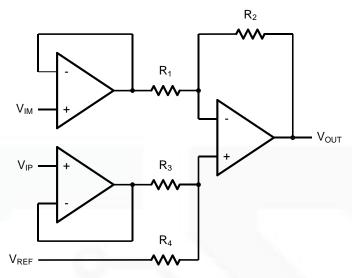


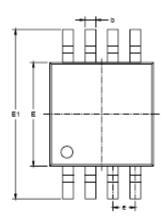
Figure 6. Instrument Amplifier



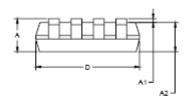


# **Package Information**

## MSOP-8



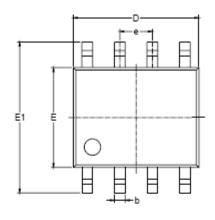




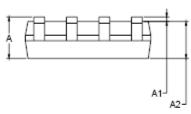
Symbol	Dimen In Milli	nsions meters	Dimensions In Inches		
-	MIN	MAX	MIN	MAX	
Α	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.008	
A2	0.750	0.950	0.030	0.037	
b	0.250	0.380	0.010	0.015	
С	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
E	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187	0.199	
e	0.650 BSC 0.026		BSC		
L	0.400	0.800	0.016	0.031	
θ	0°	6°	0° 6°		



## SOP-8



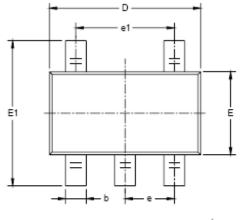


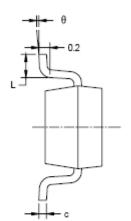


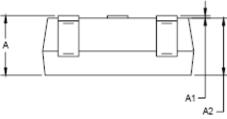
Symbol		nsions imeters	Dimensions In Inches		
,	MIN	MAX	MIN	MAX	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
e	1.27 BSC		0.050	BSC	
L	0.400	1.270	0.016	0.050	
е	0°	8°	0°	8°	



## SOT23-5



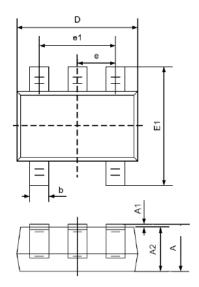


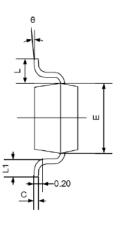


Symbol		insions imeters	Dimensions In Inches		
,	MIN	MAX	MIN	MAX	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950	BSC	0.037	BSC	
e1	1.900	1.900 BSC		BSC	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	



## SC70-5



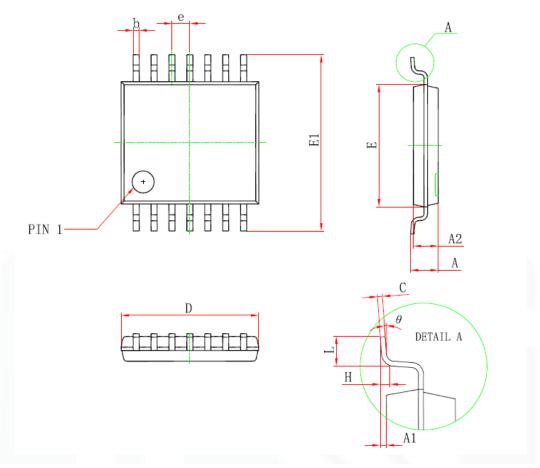


	Dimens	sions	Dimensions			
Symbol	In Milli	In Millimeters		In Inches		
	Min	Max	Min	Max		
А	0.900	1.100	0.035	0.043		
A1	0.000	0.100	0.000	0.004		
A2	0.900	1.000	0.035	0.039		
b	0.150	0.350	0.006	0.014		
С	0.080	0.150	0.003	0.006		
D	2.000	2.200	0.079	0.087		
E	1.150	1.350	0.045	0.053		
E1	2.150	2.450	0.085	0.096		
е	0.650T	ΥP	0.026TYP			
e1	1.200	1.400	0.047	0.055		
L	0.525REF		0.021REF			
L1	0.260	0.460	0.010	0.018		
θ	0°	8°	0° 8°			





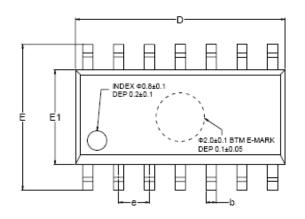
## TSSOP-14

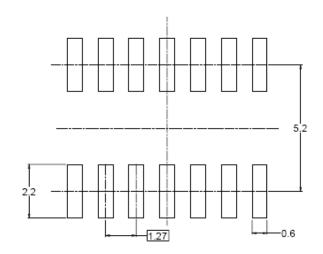


Sumbal	Dimensions In	Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
D	4.900	5. 100	0.193	0.201	
E	4.300	4.500	0.169	0.177	
b	0.190	0.300	0.007	0.012	
c	0.090	0.200	0.004	0.008	
E1	6.250	6.550	0.246	0.258	
A		1.200		0.047	
A2	0.800	1.000	0.031	0.039	
A1	0.050	0.150	0.002	0.006	
v	0.65	0.65 (BSC)		(BSC)	
L	0.500	0.700	0.020	0.028	
Н	0.25(TYP)		0.01(	TYP)	
θ	1°	7°	1 °	7°	

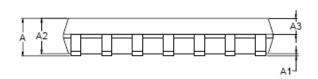


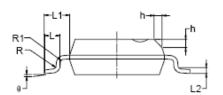
## **SOP-14**





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions In Millimeters			Dimensions In Inches		
Symbol	MIN	MOD	MAX	MIN	MOD	MAX
Α	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.25		1.65	0.049		0.065
A3	0.55		0.75	0.022		0.030
b	0.36		0.49	0.014		0.019
D	8.53		8.73	0.336		0.344
E	5.80		6.20	0.228		0.244
E1	3.80		4.00	0.150		0.157
е		1.27 BSC		0.050 BSC		
L	0.45		0.80	0.018		0.032
L1		1.04 REF			0.040 REF	
L2	0.25 BSC			0.01 BSC		
R	0.07			0.003		
R1	0.07			0.003		
h	0.30		0.50	0.012		0.020
θ	0°		8°	0°		8°